Attorney Docket No. 400.261US01

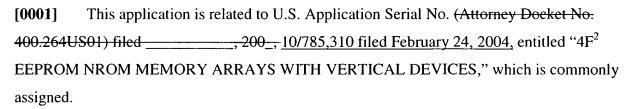
PAGE 2

Title: VERTICAL DEVICE 4F2 EEPROM MEMORY

IN THE SPECIFICATION

Please replace paragraph [0001] of page 1 with the following paragraph [0001]:

Related Application



Please replace paragraph [0023] of page 6 with the following paragraph [0023]:

[0023] Figures 5A-5D and 5B-detail vertical NAND floating gate memory array and cells in accordance with embodiments of the present invention.